

# LF2181N

## High-Side / Low-Side Gate Driver

### Features

- Floating high-side driver in bootstrap operation to 600V
- Drives two N-channel MOSFETs or IGBTs in a half bridge configuration
- 1.9A source / 2.3A sink output current capability
- Outputs tolerant to negative transients
- Wide low side gate driver supply voltage: 10V to 20V
- Logic input (HIN and LIN) 3.3V capability
- Schmitt triggered logic inputs with internal pull down
- Under Voltage Lockout (UVLO) for high and low side drivers
- Extended temperature range: -40°C to +125°C

### Description

The LF2181N is a high voltage, high speed gate driver capable of driving N-channel MOSFETs and IGBTs in a half bridge configuration. The process technology enables the LF2181N's high side to switch to 600V in a bootstrap operation.

The LF2181N logic inputs are compatible with standard TTL and CMOS levels (down to 3.3V) to interface easily with controlling devices. The driver outputs feature high pulse current buffers designed for minimum driver cross conduction.

The LF2181N is offered in SOIC(N)-8 package and operate over the extended temperature range of -40 °C to +125 °C .

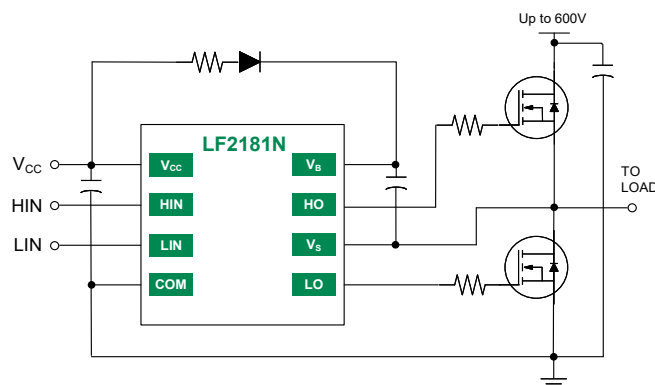


SOIC(N)-8

### Applications

- DC-DC Converters
- AC-DC Inverters
- Motor Controls
- Class D Power Amplifiers

### Typical Application



### Ordering Information

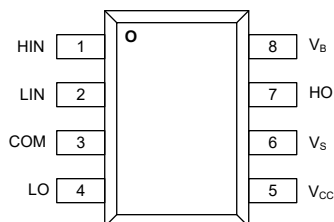
Year Year Week Week

Part#	Package	Pack / Qty	Mark
LF2181NTR	SOIC(N)-8	T&R / 2500	YYWW LF2181N LOT ID



## 1 Specifications

### 1.1 Pin Diagrams



**Top View: SOIC(N)-8**

**LF2181N**

### 1.2 Pin Descriptions

Pin#	Pin Name	Pin Type	Pin Description
1	HIN	Input	Logic input for high-side gate driver output, in phase with HO.
2	LIN	Input	Logic input for low-side gate driver output, in phase with LO.
3	COM	Power	Low-side and logic return
4	LO	Output	Low-side gate drive output
5	V <sub>CC</sub>	Power	Low-side and logic fixed supply
6	V <sub>S</sub>	Power	High-side floating supply return
7	HO	Output	High-side gate drive output
8	V <sub>B</sub>	Power	High-side floating supply

### 1.3 Absolute Maximum Ratings

Parameter	Symbol	Min	Max	Unit
High side floating supply voltage	$V_B$	-0.3	+624	V
High side floating supply offset voltage	$V_S$	$V_B - 24$	$V_B + 0.3$	V
High side floating output voltage	$V_{HO}$	$V_S - 0.3$	$V_B + 0.3$	V
Offset supply voltage transient	$dV_S/dt$	--	50	V/ns
Low side fixed supply voltage	$V_{CC}$	-0.3	+24	V
Low side output voltage	$V_{LO}$	-0.3	$V_{CC} + 0.3$	V
Logic input voltage (HIN and LIN )	$V_{IN}$	-0.3	$V_{CC} + 0.3$	V
Package power dissipation at	$P_D$	--	0.625	W
Junction Operating Temperature	$T_J$	--	+150	°C
Storage Temperature	$T_{STG}$	-55	+150	°C

Unless otherwise specified all voltages are referenced to COM. All electrical ratings are at  $T_A = 25^\circ\text{C}$

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

### 1.4 Thermal Characteristics

Parameter	Symbol	Rating	Unit
Junction to ambient	$\theta_{JA}$	200	°C/W

Thermal resistance and power dissipation ratings are measured under board mounted and still air conditions.

### 1.5 Recommended Operating Conditions

Parameter	Symbol	Min	Max	Unit
High side floating supply absolute voltage	$V_B$	$V_S + 10$	$V_S + 20$	V
High side floating supply offset voltage	$V_S$	NOTE1	600	V
High side floating output voltage	$V_{HO}$	$V_S$	$V_B$	V
Low side fixed supply voltage	$V_{CC}$	10	20	V
Low side output voltage	$V_{LO}$	0	$V_{CC}$	V
Logic input voltage (HIN and LIN)	$V_{IN}$	0	5	V
Ambient temperature	$T_A$	-40	125	°C

Unless otherwise specified all voltages are referenced to COM

**NOTE1** High-side driver remains operational for  $V_S$  transients down to -5V

### 1.6 DC Electrical Characteristics

$V_{CC}=V_{BS}=15V$ ,  $T_A = 25^\circ C$  and  $V_{COM} = 0V$ , unless otherwise specified.

The  $V_{IN}$  and  $I_{IN}$  parameters are applicable to both logic input pins: HIN, LIN. The  $V_O$  and  $I_O$  parameters are applicable to the respective output pins: HO and LO and are referenced to COM

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Logic "1" input voltage	$V_{IH}$	$V_{CC} = 10V \text{ to } 20V$ <b>Note2</b>	2.5	--	--	V
Logic "0" input voltage	$V_{IL}$		--	--	0.8	
Logic input voltage hysteresis	$V_{IN(HYS)}$		--	0.3	--	
High level output voltage, $V_{BIAS} - V_O$	$V_{OH}$	$I_O = 0A$	--	--	1.4	
Low level output voltage, $V_O$	$V_{OL}$	$I_O = 20mA$	--	--	0.2	
Offset supply leakage current	$I_{LK}$	$V_B = V_S = 600V$	--	--	50	$\mu A$
Quiescent $V_{BS}$ supply current	$I_{BSQ}$	$V_{IN} = 0V \text{ or } 5V$	20	60	150	
Quiescent $V_{CC}$ supply current	$I_{CCQ}$	$V_{IN} = 0V \text{ or } 5V$	50	120	240	$\mu A$
Logic "1" input bias current	$I_{IN+}$	$V_{IN} = 5V$	--	25	60	$\mu A$
Logic "0" input bias current	$I_{IN-}$	$V_{IN} = 0V$	--	--	5.0	
$V_{BS}$ UVLO off positive going threshold	$V_{BSUV+}$	--	8.0	8.9	9.8	V
$V_{BS}$ UVLO enable negative going threshold	$V_{BSUV-}$	--	7.4	8.2	9.0	
$V_{BS}$ UVLO hysteresis	$V_{BSUV(HYS)}$	--	--	0.7	--	
$V_{CC}$ UVLO off positive going threshold	$V_{CCUV+}$	--	8.0	8.9	9.8	
$V_{CC}$ UVLO enable negative going threshold	$V_{CCUV-}$	--	7.4	8.2	9.0	
$V_{CC}$ UVLO voltage hysteresis	$V_{CCUV(HYS)}$	--	--	0.7	--	A
Output high short circuit pulsed current	$I_{O+}$	$V_O = 0V, t \leq 10 \mu s$	1.4	1.9	--	
Output low short circuit pulsed current	$I_{O-}$	$V_O = 15V, t \leq 10 \mu s$	1.7	2.3	--	

**NOTE2** For optimal operation, it is highly recommended the input pulse (to HIN and LIN) should have a minimum amplitude of 2.5V with a minimum pulse width of 360ns.

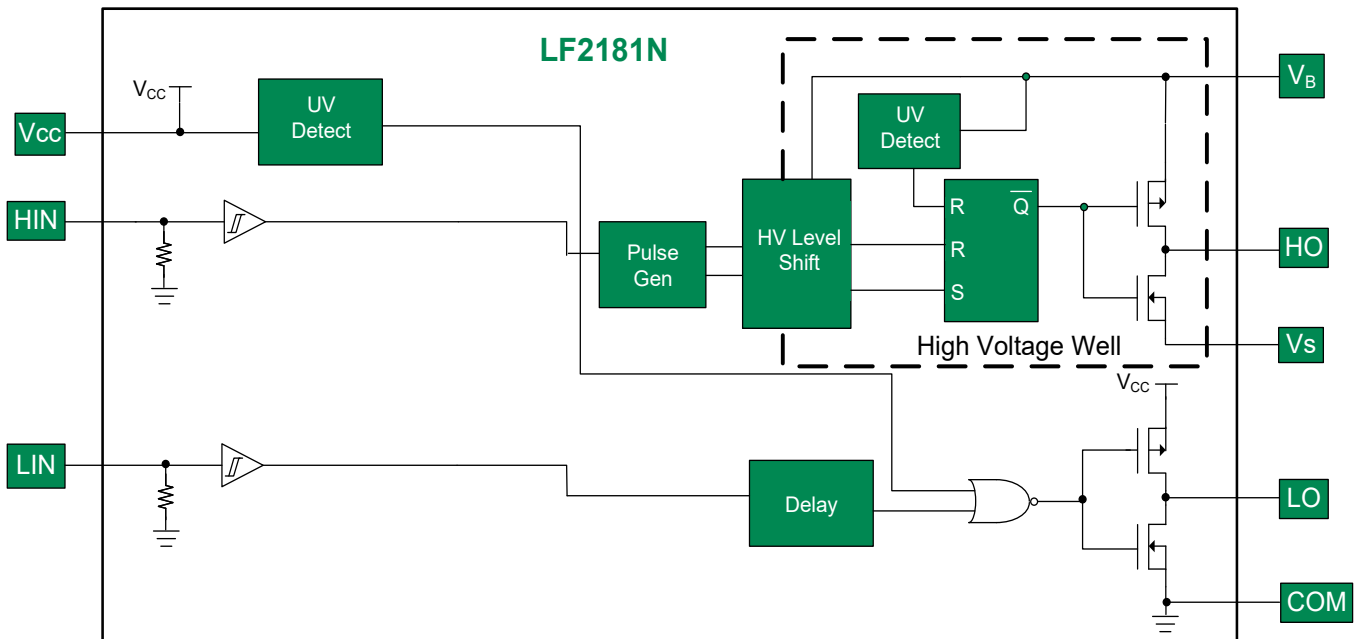
### 1.7 AC Electrical Characteristics

$V_{CC}=V_{BS}=15V$ ,  $C_L = 1000pF$ , and  $T_A = 25^\circ C$ , unless otherwise specified.

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Turn-on propagation delay	$t_{on}$	$V_S = 0V$	--	180	270	ns
Turn-off propagation delay	$t_{off}$	$V_S = 0V$ or $600V$	--	220	330	
Propagation delay matching, HO & LO turn-on/off	$t_{DM}$	--	--	--	35	
Turn-on rise time	$t_r$	$V_S = 0V$	--	40	60	
Turn-off fall time	$t_f$		--	20	35	

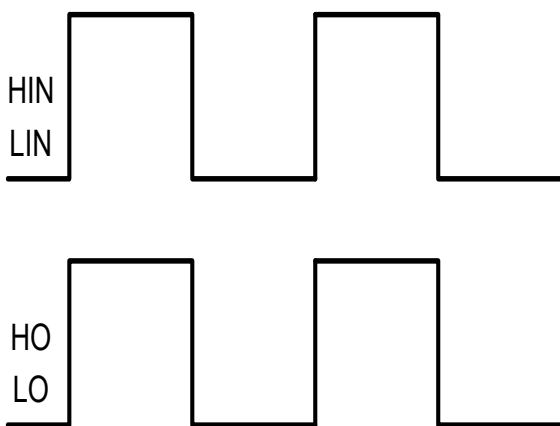
## 2 Functional Description

### 2.1 Functional Block Diagram

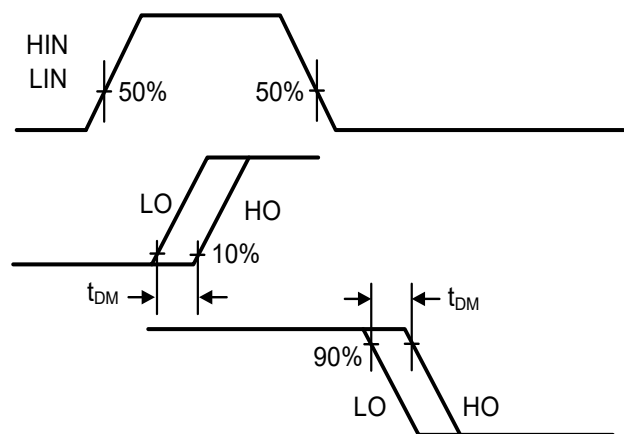


## 2.2 Timing Waveforms

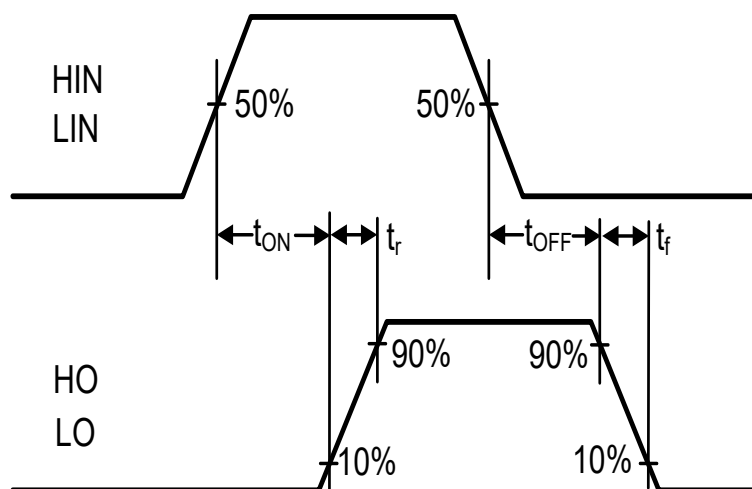
**Figure 1.** Input / Output Logic Diagram



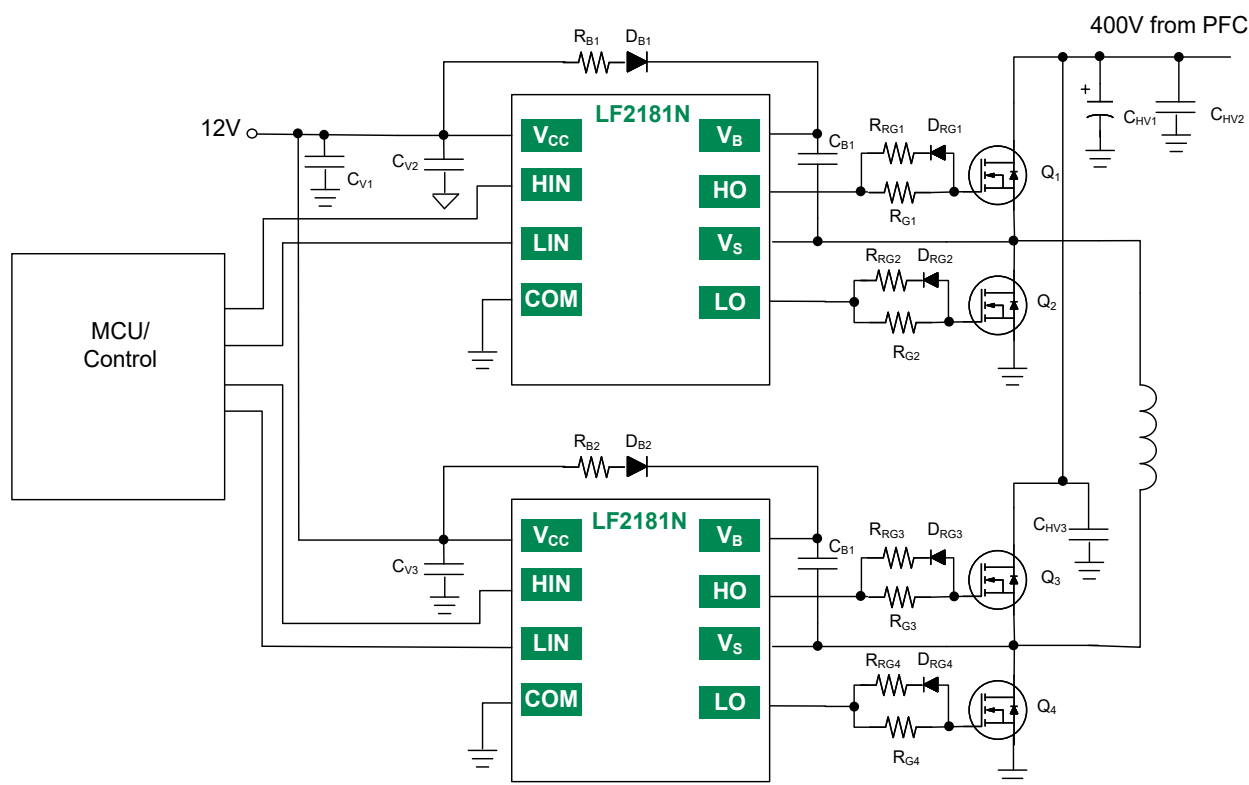
**Figure 2.** Propagation Delay Matching Diagram



**Figure 3.** Input-to-Output Delay Timing Diagram



### 2.3 Application Information



**Figure 4.** Primary side of Full Bridge converter using LF2181N

- RRG1, RRG2, RRG3, and RRG4 values are typically between 0Ω and 10Ω, exact value decided by MOSFET junction capacitance and drive current of gate driver; 10Ω is used in this example.
- It is **highly recommended** that the input pulse (to HIN and LIN) should have an minimum amplitude of 2.5V (for  $V_{CC}=15V$ ) with a minimum pulse width of 840ns.
- RG1, RG2, RG3, and RG4 values are typically between 20Ω and 100Ω, exact value decided by MOSFET junction capacitance and drive current of gate driver; 50Ω is used in this example.
- RB1 and RB2 value is typically between 3Ω and 20Ω, exact value depending on bootstrap capacitor value and amount of current limiting required for bootstrap capacitor charging; 10Ω is used in this example. Also DB1 and DB2 should be an ultra fast diode of 1A rating minimum and voltage rating greater than system operating voltage.



### 3 Manufacturing Information

#### 3.1 Moisture Sensitivity



All plastic encapsulated semiconductor packages are susceptible to moisture ingress. Littelfuse Integrated Circuits Division classified all of its plastic encapsulated devices for moisture sensitivity according to the latest version of the joint industry standard, **IPC/JEDEC J-STD-020**, in force at the time of product evaluation. We test all of our products to the maximum conditions set forth in the standard, and guarantee proper operation of our devices when handled according to the limitations and information in that standard as well as to any limitations set forth in the information or standards referenced below.

Failure to adhere to the warnings or limitations as established by the listed specifications could result in reduced product performance, reduction of operable life, and/or reduction of overall reliability.

This product carries a **Moisture Sensitivity Level (MSL)** rating as shown below, and should be handled according to the requirements of the latest version of the joint industry standard **IPC/JEDEC J-STD-033**.

Device	Moisture Sensitivity Level (MSL) Classification
LF2181N	MSL3

#### 3.2 ESD Sensitivity



This product is **ESD Sensitive**, and should be handled according to the industry standard **JESD-625**.

#### 3.3 Reflow Profile

Provided in the table below is the IPC/JEDEC J-STD-020 Classification Temperature ( $T_c$ ) and the maximum dwell time the body temperature of these surface mount devices may be ( $T_c - 5$ )°C or greater. The Classification Temperature sets the Maximum Body Temperature allowed for these devices during reflow soldering processes.

Device	Classification Temperature( $T_c$ )	Dwell Time (tp)	Max Reflow Cycles
LF2181N	260 °C	30 seconds	3



### 3.4 Board Wash

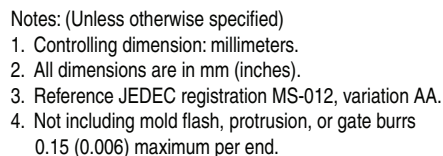
Littelfuse recommends the use of no-clean flux formulations. Board washing to reduce or remove flux residue following the solder reflow process is acceptable provided proper precautions are taken to prevent damage to the device. These precautions include but are not limited to: using a low pressure wash and providing a follow up bake cycle sufficient to remove any moisture trapped within the device due to the washing process. Due to the variability of the wash parameters used to clean the board, determination of the bake temperature and duration necessary to remove the moisture trapped within the package is the responsibility of the user (assembler). Cleaning or drying methods that employ ultrasonic energy may damage the device and should not be used. Additionally, the device must not be exposed to halide flux or solvents.





## High-Side / Low-Side Gate Driver

#### 4 Package Dimensions : SOIC(N)-8



Dimensions:  
Minimum / Maximum

## Important Notice

Disclaimer Notice - Information furnished is believed to be accurate and reliable. However, users should independently evaluate the suitability of and test each product selected for their own applications. Littelfuse products are not designed for, and may not be used in, all applications. Read complete Disclaimer Notice at <https://www.littelfuse.com/disclaimer-electronics>.

Specification: DS-LF2181N-R01  
©Copyright 2021, Littelfuse, Inc.  
All rights reserved.  
Printed in USA.  
09 / 20 / 2021